

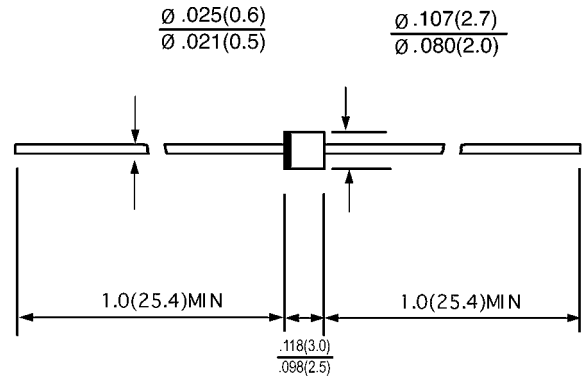


Features

- ◇ Low cost
- ◇ Glass passivated junction
- ◇ Ultra fast switching for high efficiency
- ◇ Low reverse leakage current
- ◇ Low forward voltage drop
- ◇ High current capability
- ◇ The plastic material carries U/L recognition 94V-0

Mechanical Data

- ◇ Case: JEDEC R-1, molded plastic
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.007 ounces, 0.20 grams
- ◇ Mounting position: Any

R - 1

Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

		1E1G	1E2G	1E3G	1E4G	1E5G	1E6G	UNITS
Maximum recurrent peak reverse voltage	V_{RRM}	50	100	200	400	600	800	V
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	560	V
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	800	V
Maximum average forward rectified current 9.5mm lead length, @ $T_A=75^\circ\text{C}$	$I_{F(AV)}$	1.0						A
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load @ $T_J=125^\circ\text{C}$	I_{FSM}	30.0						A
Maximum instantaneous forward voltage @ 1.0A	V_F	0.95		1.25		1.7		V
Maximum reverse current @ $T_A=25^\circ\text{C}$ at rated DC blocking voltage @ $T_A=150^\circ\text{C}$	I_R	5.0 150.0						μA
Maximum reverse recovery time (Note1)	t_{rr}	35						ns
Typical junction capacitance (Note2)	C_J	17						pF
Typical thermal resistance (Note3)	$R_{\theta JA}$	50						$^\circ\text{C/W}$
Operating junction temperature range	T_J	- 55 ----- + 175						$^\circ\text{C}$
Storage temperature range	T_{STG}	- 55 ----- + 175						$^\circ\text{C}$

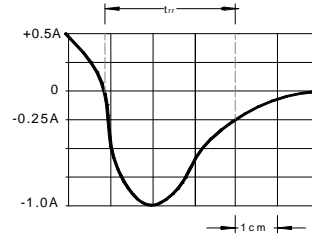
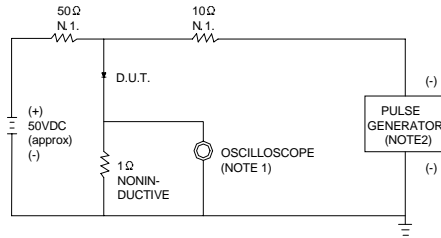
 NOTE: 1. Measured with $I_F=0.5\text{A}$, $I_R=1\text{A}$, $I_{rr}=0.25\text{A}$.

2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

3. Thermal resistance junction to ambient

Ratings AND Characteristic Curves

FIG.1 -- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC



NOTES:1.RISE TIME = 7ns MAX.INPUT IMPEDANCE = 1MΩ .22pF.
2.RISE TIME =10ns MAX.SOURCE IMPEDANCE=50 Ω .

SET TIME BASE FOR 10 ns/cm

FIG.2 -- TYPICAL FORWARD CHARACTERISTIC

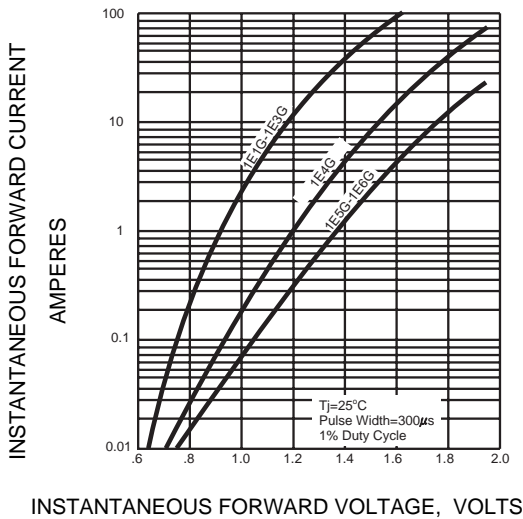


FIG.3 -- FORWARD DERATING CURVE

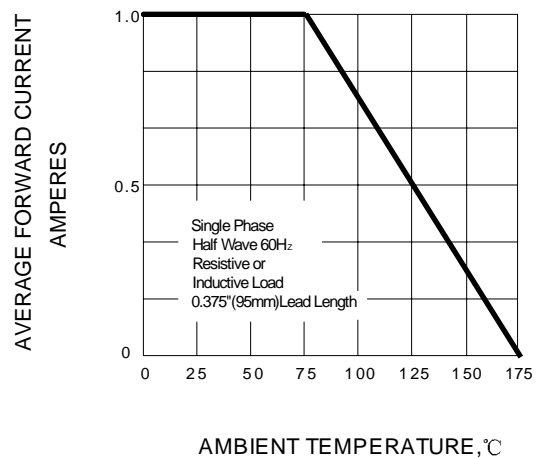


FIG.4 -- TYPICAL JUNCTION CAPACITANCE

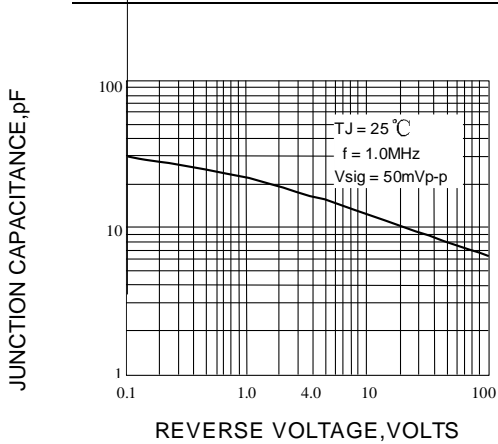


FIG.5 -- PEAK FORWARD SURGE CURRENT

